MBRA160T3

Surface Mount Schottky Power Rectifier

SMA Power Surface Mount Package

This device employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State of the art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity diodes in surface mount applications where compact size and weight are critical to the system.

Features

- Small Compact Surface Mountable Package with J-Bent Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Very Low Forward Voltage Drop
- Guard-ring for Stress Protection
- Pb–Free Package is Available

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 70 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 12 mm tape, 5000 units per 13 inch reel
- Polarity: Cathode Lead Indicated by Polarity Band
- ESD Ratings: Machine Model = C Human Body Model = 3B



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SCHOTTKY BARRIER RECTIFIER 1.0 AMPERES 60 VOLTS



SMA CASE 403D PLASTIC

MARKING DIAGRAM



- B16 = Specific Device Code
- A = Assembly Location
- Y = Year
- WW = Work Week
- = Pb–Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
MBRA160T3	SMA	5000/Tape & Reel
MBRA160T3G	SMA (Pb–Free)	5000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	60	V
Average Rectified Forward Current (At Rated V_R , $T_C = 105^{\circ}C$)	lo	1.0	A
Average Rectified Forward Current (At Rated V_R , $T_C = 70^{\circ}C$)	lo	2.1	A
Non–Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	60	A
Storage/Operating Case Temperature	T _{stg} , T _C	-55 to +150	°C
Operating Junction Temperature	TJ	-55 to +125	°C
Voltage Rate of Change (Rated V_R , $T_J = 25^{\circ}C$)	dv/dt	10,000	V/μs

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

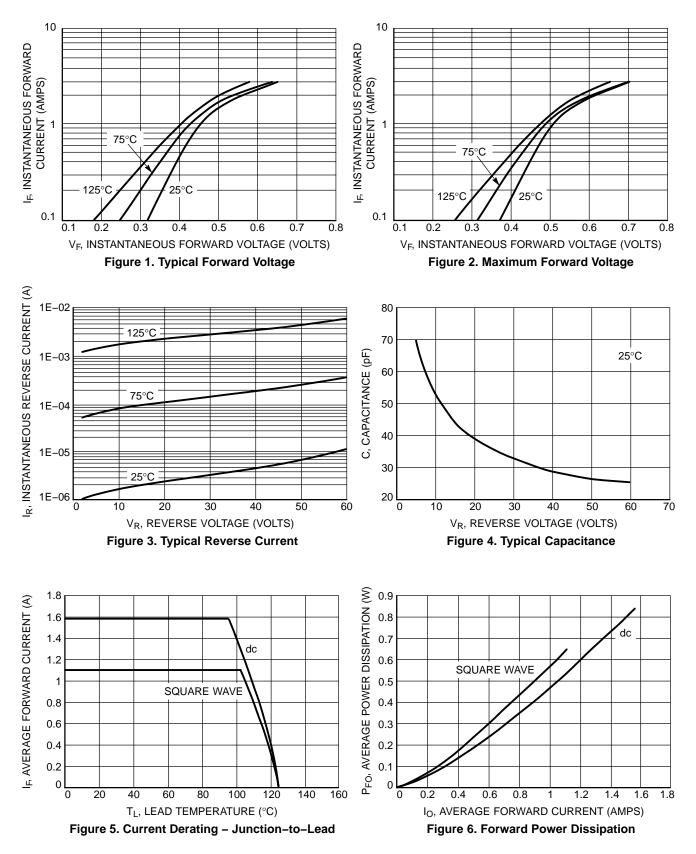
Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead (Note 1) Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JL}$ $R_{ heta JA}$	35 86	°C/W

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 2)		V _F	$T_J = 25^{\circ}C$	T _J = 125°C	V
	(I _F = 1.0 A)		0.510	0.475	
Maximum Instantaneous Reverse Current		I _R	T _J = 25°C	T _J = 125°C	mA
	(V _R = 60 V)		0.2	10	

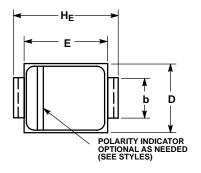
Mounted on 2" Square PC Board with 1" Square Total Pad Size, PC Board FR4.
Pulse Test: Pulse Width ≤ 250 μs, Duty Cycle ≤ 2.0%.

MBRA160T3



PACKAGE DIMENSIONS

SMA CASE 403D-02 ISSUE C



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

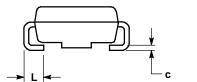
CONTROLLING DIMENSION: INCH.
403D-01 OBSOLETE, NEW STANDARD IS 403D-02.

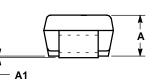
PIN 1. CATHODE (POLARITY BAND) 2. ANODE

STYLE 1:

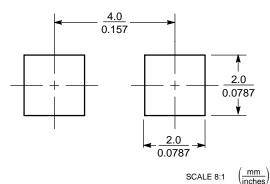
		MILLIMETERS			INCHES			
	DIM	MIN	NOM	MAX	MIN	NOM	MAX	
	Α	1.91	2.16	2.41	0.075	0.085	0.095	
	A1	0.05	0.10	0.15	0.002	0.004	0.006	
	b	1.27	1.45	1.63	0.050	0.057	0.064	
	С	0.15	0.28	0.41	0.006	0.011	0.016	
	D	2.29	2.60	2.92	0.090	0.103	0.115	
	E	4.06	4.32	4.57	0.160	0.170	0.180	
	HE	4.83	5.21	5.59	0.190	0.205	0.220	

L 0.76 1.14 1.52 0.030 0.045 0.060





SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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